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Abstract

The central-field models and the theoretical analyses for some atomic processes in hot, dense plasmas are reviewed. The qualitative trends of the density- and temperature-dependent properties of plasma particles, which could be used for diagnostics of the plasma, are described.
§1. INTRODUCTION

Hot, dense plasmas have vigorously been studied in various fields in physics such as plasma physics, astrophysics, atomic physics and solid state physics, in particular in connection with the inertia confinement fusion (ICF) study.

In the ICF research, description of the plasma under extreme conditions such as high temperature \( T_e > 10^6 \) K and high density \( N_e > 10^{24} \) cm\(^{-3} \) in terms of the microscopic atomic processes is required when modelling the plasma. Since the ICF plasma is usually produced in a very short-time scale \( \approx 10^{-9} \) sec), it is neither homogeneous nor steady. This means that the motion of nonthermal electrons and ions accompanying mutual collision or indirect interaction through the emission and absorption of photons determines the density and temperature in each position and time. This situation is very different from low density plasmas observed in solar corona or the Tokomak, where the effect of the surrounding plasma on a test atom can be considered to be a small perturbation. These low density plasmas, where collision processes are dominant, have been studied by use of the perturbation theory for the atomic processes in the plasma.

Modification of the models based on the thermal equilibrium such as corona equilibrium or the local thermal equilibrium (LTE) may be required in the study of an unsteady plasma such as the ICF one. Moreover, one has to introduce the molecular or solid-state effects into the model in describing the atomic properties of ions in dense plasmas, since the average internuclear distance in these plasmas...
becomes much smaller than that in the normal solid state: The radii of most atomic orbitals are larger than the internuclear distance.

A large number of papers on hot, dense plasmas so far been published concern with a variety of subjects such as radiation or particle transport processes, plasma spectroscopy, equation of states, atomic processes, etc. One component plasma has extensively been studied as an ideal system (Ichimaru 1977).

Even if one confines the subjects to problems in diagnosing hot, dense plasmas through the analysis of the line broadening and line shift in X-ray spectra observed, there are two main themes related to atomic physics. One is the structure of ions in a plasma as a source of light and the other is the atomic processes related to energy transport and opacity. Various models with the assumption of the thermal equilibrium for the plasmas have been proposed. Most of them are the central-field atomic model which yields the single-electron energies of ions in a plasma.

This note presents a brief survey on the atomic models and the qualitative trends of the density- and temperature-dependent properties of ions in a hot, dense plasma. Recently some review papers on atomic physics in hot, dense plasma have been published (More, 1981, Weisheit 1981, Gupta and Rajagopal, 1982; papers in JQSRT 27, 1982). Details of the studies on dense plasmas including the subject on energy transport and opacity can be found in these articles.
§ 2. CENTRAL-FIELD MODELS FOR ATOMS IMMERSED IN A PLASMA

A test charge immersed in a plasma receives various types of the perturbations from surrounding plasma particles. One of significant perturbations is the screening of the nuclear charge by free electrons as a result of the plasma polarization effect, i.e. departure from the uniform distribution of electrons and ions near the test charge. Another is the fluctuation of the microfield around the test charge due to the instantaneous motion of ions and electrons and their collective motion called as the plasma oscillation. In addition to these effects, the perturbation due to electron impact is also an important factor to characterize the level population or life time of excited states of the ion especially for low-density plasmas.

As the density of a plasma increases, the screening of the nuclear charge by free electrons becomes significant. On the other hand, this effect of the screening decreases when the temperature becomes high, since the ion can move freely over the potential barrier due to the surrounding plasma media. In order to specify such plasma condition instead of two parameters of the density and temperature, one often uses a dimensionless plasma parameter \( \Gamma \) which is the ratio of the average Coulomb energy for ions to the temperature of the plasma, defined as

\[
\Gamma = \frac{Z_i^* e^2}{R_i kT},
\]

where \( Z_i^* \) and \( R_i \) are the average charge and ion-sphere radius of ions, respectively. The ion-sphere radius is given by
where \( N_e \) is the electron density.

The structure of a test atom immersed in a plasma has extensively been investigated by using the central-field models with appropriate electrostatic potentials for the atom. The electrostatic potential \( V \) is obtained as a solution of the Poisson equation written as

\[
\nabla^2 V = -4\pi\rho
\]

if the average charge distribution both the positive and negative charges around the atom with an appropriate model is given. Since the average charge distribution \( \rho \) in Eq. (3) heavily depends on the plasma condition, there certainly exists a critical condition at which a particular model breaks down. In the following, various central-field models used in diagnosing a plasma are described briefly.

2-a) Debye-Hückel Model

This model starts with the non-uniform statistical distribution of the charged particles around a test charge \( Z_e \). Using Boltzmann's law, the number of \( a \)-th particle having the charge \( Z_{ae} \) as a function of \( r \) is written as

\[
N_a(r) = N_{a0} \exp \left( -\frac{Z_{ae} e}{kT_a} V(r) \right)
\]

where \( N_{a0} \) is the uniform value and \( V(r) \) is the electrostatic potential. The DH average charge distribution \( \rho_{DH}(r) \) can be obtained as
\[ \rho_{DH}(r) = e \sum_a Z_a N_a(r) = e \sum_a Z_a N_{a0} \exp \left( -\frac{Z_a e^2}{kT_a} V(r) \right) . \]  \hspace{1cm} (5)

The condition that a plasma be neutral leads to the following relation,

\[ \sum_a Z_a N_a = 0 . \]  \hspace{1cm} (6)

The exponential part in Eq. (5) can be expanded to the first-order of \( V \) under the condition that \( kT >> |V| \), i.e. \( \Gamma << 1 \). By inserting this linearized \( \rho_{DH}(r) \) with respect to \( V \) into Eq. (3), the DH potential \( V_{DH}(r) \) is obtained in the familiar form,

\[ V_{DH}(r) = \frac{Ze^2}{r} e^{-\frac{r}{D}} . \]  \hspace{1cm} (7)

where \( D \), the Debye length, is given by

\[ D = \frac{1}{[4\pi e^2 (\sum_a Z_a^2 N_{a0})/kT]^{1/2}} . \]  \hspace{1cm} (8)

The DH potential could be a good approximation for low density and high temperature plasmas because of the linearized \( \rho_{DH}(r) \).

2-b) Ion-Sphere (IS) Model

In a strongly compressed plasma, the density of the free electrons around the ion is very high. The ion-sphere (IS) model is constructed from the assumption that electrons are uniformly distributed in the ion sphere, so that \( \rho_{IS}(r) \) is written as
\[
\rho_{IS} (r) = \begin{cases} 
Z/(\frac{4\pi}{3} R_i^3) , & \text{when } r \leq R_i \\
0 , & \text{when } r > R_i 
\end{cases} 
\] (9)

where \( R_i \) is the ion sphere radius. The IS potential is obtained by use of the Poisson equation in the following form,

\[
V_{IS} (r) = \begin{cases} 
\frac{Ze}{r} - \frac{Ze}{2R_i} \left( 3 - \frac{r^2}{R_i^2} \right) , & \text{when } r \leq R_i \\
0 , & \text{when } r > R_i 
\end{cases} 
\] (10)

It is noted that \( R_i \) depends only on the density of the plasma. However, as nuclei are assumed to be fixed in this model, it can be expected that this model yields good results for low temperature and high density plasmas.

2-c) Thomas-Fermi (TF) Model

This model is one of the ion-sphere models which are suitable for dense plasmas. The TF theory at zero temperature has well been known to be useful in the study of highly compressed matter, since the atomic electrons can be confined within an atomic sphere by introducing the cut off condition for the electron distribution, where the charge at the boundary remains non-zero. The zero-temperature TF theory has been extended to the finite temperature TF theory by some authors (Feynman et. al. 1949 and Cowan et. al. 1957). If one replaces the atomic electrons in a sphere by the finite-temperature semi-classical gas, the TF
distribution $\rho_{TF}(r)$ is written as

$$
\rho_{TF}(r) = \frac{8\pi}{h^3} \int_0^{\infty} \frac{P^2 dP}{\exp \left[ \frac{P^2}{2m} - eV(r) - \mu/kT \right] + 1},
$$

(11)

where the chemical potential $\mu$ is determined by the requirement that the cell be neutral:

$$
\int \rho_{TF}(r) d^3r = Z.
$$

(12)

By solving Eq. (11) and Eq. (3) self-consistently, the $V_{TF}(r)$ is obtained numerically. The TF theory has widely been applied to the dense plasmas with various modifications.

2-d) Average Atom (AA) Model

The average atom model (Chandrasecker 1939) is essentially based upon the assumption that atomic electrons are distributed in the single-electron levels according to the Fermi statistics. This assumption leads to the non-integer occupation number for the $n\ell$ state given by

$$
N_{n\ell} = \frac{2(2\ell + 1)}{\exp \left[ \frac{\varepsilon_{n\ell} - \mu}{kT} \right] + 1},
$$

(13)

where $\varepsilon_{n\ell}$ is the orbital energy. The single-electron levels for an atom can be obtained as solutions of the Schrödinger equation with an appropriate screened potential. The average atom model has been used for plasma modelling because of its simple and unified treatment of the structure for various ionization stages of an ion immersed in a plasma.
However, this model cannot be used to identify the lines from atoms in different ionization stages or to calculate the ratio of intensities for lines because this model leads to a fictitious atom which consists of the average of all the possible ionization stages of the real atom.

2-d-1) Self-Consistent-Field-Average-Atom (SCFAA) Model

Rozsnyai (1972) has proposed a self-consistent-field-average-atom (SCFAA) model, where all electrons are assumed to be confined within a sphere having the radius $R_i$. The relativistic Hartree-Fock-Slater (RHFS) method is used to determine the single-electron levels for the bound electrons. The density of the bound electrons $\rho_b$ is calculated with the RHFS orbitals and the Fermi distribution function. On the other hand, density of free electrons $\rho_f$ is determined by use of the relativistic expression of the finite temperature TF theory. The total potential including the exchange and the correlation potentials is calculated using $\rho_b$ and $\rho_f$. This total potential written as

$$ V(r) = \frac{Z_e}{r} + V_b(r) + V_f(r) + V_{\text{ex}}(r) + V_{\text{cor}}(r) $$

is used in the RHFS equation. The calculation terminates when the self-consistent potential is obtained. This model has been used to calculate various physical quantities of ions in a hot, dense plasma such as the line shift and the photoabsorption cross section by Rozsnyai.

2-d-2) Screened Hydrogenic Ionization (SHI) Model

Application of the semi-classical WKB theory to
hydrogenic systems yields analytic expressions for the energy and expectation values for the coordinate or momentum operators. These expressions except for the energy are different from those obtained with the quantum mechanics. The screened hydrogenic ionization (SHI) model (More 1981) is an extension of the WKB results for hydrogenic systems to many-electron atoms, where the effective charges are introduced into the WKB expression for the energy so that it becomes a good approximation for each orbital energy in many-electron atoms. In this model, the sub-shell splitting of orbital energies between \( n \ell \) and \( n \ell' \) is neglected. The SHI orbital energy with a principal quantum number \( n \) for an atom has the form

\[
E_n = E_0^n - \frac{Q_n^0 e^2}{2a_0 n^2} ,
\]

where \( E_0^n \) is the energy-shift with outer screening, \( Q_n \) is the effective charge due to the inner screening and \( a_0 \) is the Bohr radius. In the WKB approximation, a shell is expressed by a classical orbit with the radius \( r_n \) as

\[
r_n = \frac{a_0 n^2}{Q_n} .
\]

\( Q_n \) depends on the electron population \( \{ P_m \} \) of the shells inside \( r_n \), whereas \( E_0^n \) depends on \( \{ P_m \} \) of the shells outside \( r_n \). This dependence of \( Q_n \) and \( E_0^n \) are represented with a linear approximation with respect to \( P_m \) as
\[ Q_n = Z - \sum_{m<n} \sigma(n, m) P_m - \frac{1}{2} \sigma(n, n) P_n \] (17)

and

\[ E_n^0 = \frac{1}{2} \sum_{m<n} \frac{e^2}{r_n} \sigma(n, n) P_n + \sum_{m>n} \frac{e^2}{r_m} P_m \sigma(m, n), \] (18)

where \( \sigma(n, m) \) is the screening coefficient which describes the screening of the \( n \)-th shell by the \( m \)-th shell electrons. A set of screening coefficients \( \{ \sigma(m, n) \} \) can be calculated using the first-order perturbation theory for hydrogenic wavefunctions.

The SHI model essentially deals with a set of electron populations of various shells \( \{ P_m \} \) combined with screening coefficients \( \{ \sigma(m, n) \} \). If the thermal equilibrium is assumed for a plasma, the average population (occupation) number \( \overline{P_n} \) may be written as

\[ \overline{P_n} = \frac{2n^2}{\exp [(E_n - \mu)/kT] + 1} \] (19)

This model has also been applied to diagnostics of the non-LTE plasmas such as the ICF one because the much reduction of the calculation for such a complex system is possible with this model.

2-e) Intermediate Models

The limitation of the DH model is that it can be applied only to low-density and high-temperature plasmas, whereas the IS model is a good approximation for high-density and low-temperature ones. There are some models which cover the intermediate plasma conditions, where both
the DH and the IS models are not valid. Here, the Thomas-Fermi-ion-core (TFIC) model (Stwert and Pyatt 1966) and the effective screening model (Singwi 1977; Gupta and Rajagopal 1979) are described.

2-e-1) TFIC Model

In the ion-sphere (IS) model, each ion has the ion sphere which contains enough free electrons to maintain charge neutrality in the sphere. However, the effect of the position correlation between ions moving in various positions is not contained in this model. The TFIC model consists of the TF model for free electrons, the average atom (AA) model for bound electrons and the Maxwell-Boltzmann distribution for neighboring ions. The total charge distribution $\rho(r)$ is expressed as a sum of the charge distributions for bound electrons $\rho_b(r)$, free electrons $\rho_f(r)$ and neighboring ions $\rho_i(r)$ in the following,

$$\rho(r) = \rho_b(r) + \rho_f(r) + \rho_i(r) ;$$  \hfill (20)

where

$$\rho_b(r) = \frac{1}{4\pi} \sum_{n^2} \frac{2(2l + 1)}{\exp[(\delta_{n^2} - \mu)/kT_e] + 1} |R_{n^2}(r)|^2 ,$$ \hfill (21)

$$\rho_f(r) = \frac{8\pi}{h^3} \int_{0}^{\infty} \frac{p^2 dp}{\exp[(p^2/2m) - eV(r) - \mu/kT_e] + 1}$$ \hfill (22)

and

$$\rho_i(r) = \rho_0 \exp\left[-\frac{Ze}{kT_i} V(r) \right].$$ \hfill (23)

The radial part of the wave function $R_{nl}(r)$ is obtained as a
solution of the Schrödinger equation using the potential \( V(r) \). The Poisson equation (3) and Eqs. (20)-(23) combined with the Schrödinger equation are solved iteratively until the self-consistent solution for \( \rho(r) \) and \( V(r) \) is obtained. This model has been used to explain the lowering of the ionization potential in the intermediate region of the plasma conditions (Stwert et. al. 1966).

2-e-2) Effective Screening Model

The effective screening model deals with the effective potential which is obtained through the density functional approach for the formulation of the free-energy framework. The effective screening potential (Gupta et. al. 1979) is expressed as

\[
V_{\text{eff}}(r, n_e, T_e) = \frac{2e}{\pi} \int_0^{\infty} dq \left( \frac{\sin qr}{qr} \right) \frac{1}{1 - (4\pi e^2/q^2) \chi(q, n_e, T_e)},
\]

where \( \chi(q, n, T) \), the RPA Lindhard function, is given by

\[
\chi(q, n, T) = -2 \int \frac{d^3p}{(2\pi)^3} \frac{f(p + q) - f(p)}{p^2/2m - (p + q)^2/2m},
\]

and

\[
f(p) = \frac{1}{\exp \left( \frac{p^2}{2m} - \mu \right)/kT + 1},
\]

For \( q \rightarrow 0 \) limit in Eq. (24), \( V_{\text{eff}}(r) \) reduces to the screened Coulomb potential with the effective screening parameter \( \xi(n_e, T_e) \) in the following form,
\[ V_{eff}(r, n_e, T_e) \rightarrow V_{\xi}(r) = \frac{Ze^2}{\epsilon} e^{-\xi(n_e, T_e)/r} \quad (27) \]

The parameter \( \xi(n_e, T_e) \) also reduces to a constant corresponding to the DH and the TF values for high temperature and low temperature limits, respectively:

\[ \xi(n_e, T_e) \rightarrow \xi_{DH} \quad T_e \rightarrow \infty \quad (28) \]

and

\[ \xi(n_e, T_e) \rightarrow \xi_{TF} \quad T_e \rightarrow 0 \quad (29) \]
3. STRUCTURE OF IONS AND ATOMIC PROCESSES

In this section, the density and temperature effects on the structure of ions and some atomic processes in hot, dense plasmas are described.

3-a) Energy Levels

As the nuclear charge is fairly screened in the DH potential, the values of the most screened potentials based on the corresponding central-field model described in §2 as a function of $r$ always lie between those of the DH and the pure Coulomb potentials. The single-electron energies for ions are obtained as solutions of the Schrödinger equation with these potentials.

The shield of the nuclear charge leads to a short range potential which allows only a finite number of bound states. This means that highly excited bound states (Rydberg states) for a pure Coulombic potential dissolve into the continuum sea of states in the system. This fact is known as 'continuum lowering' or 'pressure ionization' as a result of the screening of the nuclear charge by free plasma electrons. In addition to the continuum lowering of energy levels, separation of the energy between neighboring states decreases as the screening of the nuclear charge increases. A screened Coulomb potential yields the sub-shell splitting of the energy levels belonging to the $n\ell$ states for which azimuthal quantum numbers are different. The same type of the splitting of energy levels is always observed in the Hartree-Fock (HF) orbital energies of an isolated atom since the HF potential is a non-Coulombic potential.

Although the DH model is a good approximation for low
density and high temperature plasmas, it has been examined over a wide range of the plasma conditions by some authors (Rogers et al. 1971, Rousselet et al. 1974). The dependence of the DH energy levels of lower-lying and higher-lying states on the screening lengths (Rogers et al, 1971) is shown in Fig. 1 and 2, respectively. Characteristic behaviors of the bound levels such as the continuum lowering and the decrease of the spacing of energy levels mentioned above are seen from these figures. It is also seen that no bound state, as is expected, exists in the high-density limit.

3-b) Oscillator Strength and Photoabsorption Cross Section

The absorption oscillator strength $f(b \rightarrow a)$ and the spontaneous emission rate $A(b \rightarrow a)$ are related to the opacity and line strengths of the observed spectra. The oscillator strength $f(b \rightarrow a)$ is connected with the spontaneous emission rate $A(b \rightarrow a)$ through the relation,

$$f(b \rightarrow a) = \frac{2m\omega_{ba}}{3\hbar} \langle b | r | a \rangle^2 = \frac{mc^3}{2\pi^3\omega_{ba}} A(b \rightarrow a),$$

where $m$ is the electron mass, $c$ is the velocity of light, $\omega_{ba}$ is the transition frequency and $\langle b | r | a \rangle$ is the transition matrix element in the dipole approximation.

The $f$-value or the $A$-value for bound-bound transitions as a function of the density and temperature has been calculated with the DH potential for hydrogenic systems (Roussel et al. 1974, Weisheit et al. 1974, Shore 1975 and Hönne et al. 1982). They showed that the $f$-value or the $A$-value for a transition decreases rapidly when the Debye screening length becomes as small as a few times the
critical screening length of the upper level. This is shown in Fig. 3. Weisheit and Shore (1974) have calculated the oscillator strengths and photoabsorption cross sections for the ls - np transition for all the bound and continuum states using the DH model. The calculated results of them show that the decrease and sudden drop of the f-value at the threshold energy.

Höhne et. al. (1982) re-examined the behavior of the oscillator strength for the bound-bound and bound-free transitions and claimed the results of Weisheit and Shore, namely, the drastic reduction of the oscillator strength at threshold, where the smooth connection of the f-value between the bound-bound and bound-free transitions around the threshold was not observed. The conclusion of Höhne et. al. is that the averaged oscillator strength given by

$$\sigma_n^\lambda(\omega) = \sum_{q'=1} f_{nq} \frac{q'}{E_{q'} - E_{n\lambda}} \left| \frac{dE_{q'}}{dq'} \right|^{-1}$$

should be used for a non-Coulombic potential such as the DH one, since the application of the Coulomb result for the differential oscillator strength df/dE to non-Coulombic systems leads to an incorrect result. The calculated results of the averaged oscillator strengths $\sigma_n^\lambda(\omega)$ for the DH potential by Höhen et. al. are shown in Fig. 4 together with those for the pure Coulomb potential. It is seen from Fig. 4 that the curve of $\sigma_n^\lambda(\omega)$ for the DH and the pure Coulomb potentials are very close to each other.

Characteristic behavior of the photoabsorption cross section for a screened potential is the $k^{2\lambda+1}$ behavior near
the threshold energy (Wigner 1948). Shore (1975), however, showed that since near-resonant wavefunctions for energies with a narrow interval between the DH and the pure Coulomb thresholds have the enhanced amplitude within the potential well interior, the photoabsorption cross section increases in this region of the photon energy. The same result has also been obtained by Höhne et. al. (1982).

3-c) Shift of Spectral Lines

The shift of spectral lines has been calculated with various atomic models for an emissive ion in a plasma. As has been mentioned before, the energy difference between the states decreases as the screening of the nuclear charge by free electrons increases. This means that the lines are shifted toward the lower frequency side, that is, the red shift. On the other hand, the plasma polarization shift (PSS) theory (Griem 1974) which deals with the effective charge of the ion using the perturbation theory gives the blue shift for the resonance line of the hydrogenic helium ion.

Skupsky (1980) has calculated the magnitude of the line shift with the modified Thomas-Fermi-ion-core (TFIC) model for the 2p→1s transition of a hydrogenic impurity neon in deuterium and tritium plasma, where the charge distribution of the bound electron is obtained with the statistical average of the $|\psi_{1s}|^2$ and $|\psi_{2p}|^2$. The calculated shifts of the Lyman-α line for hydrogenic neon in the plasma are compared with those using the DH, the IS and the effective screening models in Fig. 5. In the low density limit, Skupsky's result shows the characteristic oscillation and
the blue shift. However, in the high density limit, the line
shift with his model becomes the red shift which is the
same trend of the line shift as other models such as the DH
one. This behavior of the line shift, namely, the blue shift
in the low density limit and the red shift in the high
density limit has been confirmed by the SCFAA calculation
(Rozsnyai 1975). In Fig. 5, the calculated results with
different models (Cauble 1982, Gupta et. al. 1981) are also
compared. Cauble's result is based on the plasma
polarization shift theory, while Gupta et. al. used the
effective screening model. These calculations of the line
shift for hydrogenic neon in a hydrogen plasma give the red
shift with the intermediate values between that of Skupsky
and the DH value for all densities of the plasma considered.

Concerning the profile of spectral lines, there have
been proposed some methods other than the plasma
polarization shift theory (Griem 1974) to calculate both the
shift and width of lines at the same time. The problems of
the broadening of the spectral lines are closely related to
opacity in hot, dense plasmas. Using the perturbation
expansion of the partition function for the multicomponent
plasmas, Nakayama et. al. (1964) has derived a pseudo-
Schrödinger equation containing the complex potential.
Yamamoto et. al. (1980) have studied the complex level shift
which includes both the shift and width, with the quantum
scattering theory based on the impact approximation.
However, it seems that problems lie in the application of
such method based on the perturbation theory to dense
plasmas.
3-d) Free-Free Transition

Free-free transitions are important processes in problems for the transport and loss of the radiation in plasmas. Especially, the free-free photoabsorption plays an important role in heating plasmas by laser.

The cross section $\sigma$ for the free-free transition is often expressed by the Gaunt factor $G$ as

$$G = \frac{\sigma}{\sigma_{cl}},$$  \hspace{1cm} (32)

where $\sigma_{cl}$ is the Kramers classical cross section,

$$\sigma_{cl} = \frac{16\pi}{3\sqrt{3}} \frac{a^3}{3} \frac{h^2}{2m} \frac{Z^2}{W_0 \nu},$$  \hspace{1cm} (33)

Here, $\alpha$ is the fine structure constant, $W_0$ is the energy of the incident electron and $\nu$ is the frequency of the photon emitted. The general expression for $G$ in the non-relativistic Born approximation has been given by Grant (1958).

The Gaunt factor can be obtained in an analytic form if an analytic form such as the Yukawa-type function is assumed for the electron-ion potential in the Born approximation. Suppose the potential $V(r)$ is constructed as a superposition of the two Yukawa-type potentials, given by

$$V(r) = e \left[ \frac{Z - N_b}{r} e^{-\alpha r} + \frac{N_b}{r} e^{-\beta r} \right],$$  \hspace{1cm} (34)

where $Z$ is the nuclear charge, $N_b$ is the average number of bound electrons and $\alpha$ and $\beta$ are screening parameters, the Gaunt factor $G$ has the following analytic form,
\[ G = g(q_{\text{max}}) - g(q_{\text{min}}), \]  

where

\[ g(q) = \frac{\sqrt{3}}{\pi} \left[ -\frac{q^2}{2(q^2 + \alpha^2)} + \frac{1}{2} \ln(q^2 + \alpha^2) \right. \]

\[ + \frac{N_b}{(Z - N_b)^2} \left\{ -\frac{q^2}{2(q^2 + \beta^2)} + \frac{1}{2} \ln(q^2 + \beta^2) \right\} \]

\[ + \frac{1}{2} \frac{N_b}{(Z - N_b)} \left\{ \ln(q^2 + q^2\alpha^2 + q^2\beta^2 + \alpha^2\beta^2) \right. \]

\[ + \frac{\beta^2 + \alpha^2}{\beta^2 - \alpha^2} \ln\frac{q^2 + \beta^2}{q^2 + \alpha^2} \left\} \right]. \]  

\[ (36) \]

\( q_{\text{max}} \) and \( q_{\text{min}} \) mean the maximum and minimum values of the momentum transfer \( q \), respectively.

Rozsnyai (1979) has derived Eq. (36) and calculated the Gaunt factor averaged over the energy distribution of the free electrons in cecium plasmas at \( T_e = 100 \) eV and 1 KeV, using the potential in a form of Eq. (34) where the parameters \( \alpha \) and \( \beta \) were determined so that the values of \( V(r) \) becomes the same as those of the SCFAA potential at two chosen points of \( r \). His results show that the Gaunt factor increases in the high energy photon region and decreases in the soft photon region as the density becomes high. When the density increases, the relative drop of the Gaunt factor toward the low-frequency side of the photon energy is observed, since available upper states decrease.

Recently Lamoureux et. al. (1982) have investigated the
free-free emission in a cesium plasma of the normal density at $kT=1$ keV. They have calculated the Gaunt factor not only in the Born approximation but also with the relativistic partial wave expansion method using both the Thomas-Fermi potential $V_{TF}$ and the SCFAA one $V_{SCFAA}$ obtained by Rozsnyai (1979) for this system. The calculated results at $W_0=1$ keV are shown in Fig. 6. The values of $G^B$ were obtained with the Elwert factor in the Coulomb Born approximation. It is noted that the Born-Elwert approximation for $G$ is valid in a relatively wide range of the incident electron energies comparing with the Born approximation. $G^B_{SCFAA}$ denotes the results obtained with the expression for the Gaunt factor in Eq. (35). $G_{TF}$ and $G_{SCFAA}$ indicate the results based on the relativistic partial wave expansion method for $V_{TF}$ and $V_{SCFAA}$, respectively.

It is seen from Fig. 6 that values of $G^B_{SCFAA}$ are smaller than those of $G^B$. This indicates that the screening of the nuclear charge by electrons reduces the Gaunt factor. The calculated results of $G^B_{SCFAA}$ in the Born approximation, however, are large compared with those of $G_{SCFAA}$ using the numerical partial wave method, although the same SCFAA potential is used. This fact shows the importance of the method of calculation rather than the potential in the calculation of the Gaunt factor.

3-e) Collision Processes Between an Electron and an Ion

When an ion with the nuclear charge $Z_e$ and $N$ electrons is immersed in a hot, dense plasma, the electronic excitation process of the ion by the collision of an incoming electron,
\[ e + A^{q+} \rightarrow e + (A^{q+})^* \]  

(37)

and

\[ q = Z - N \]  

(38)

is significantly affected by the presence of the positive and negative charges near the ion. In vacuum, the excitation of an ion by electron impact is treated as the collision process strongly influenced by the long range Coulomb potential between the electron and the ion. In a hydrogen plasma, we should take into account the effect of the electrostatic potential due to electrons and protons. Usually some of these electrons move slower and others faster, as compared with speed of the impact electron. Both electrons and protons form the spherically asymmetric potentials for the projectile electrons.

At present, no trial has been made for the estimation of the electronic excitation cross section which includes such time dependent, spherically asymmetric potential effects. Only the approaches using the averaged spherically symmetric potential have been made for the excitation processes of one-electron ion with the charge Ze (Hatton, Lane and Weisheit, 1981) and the same processes for Z=10, i.e.,

\[ e + Ne^{q+} \rightarrow e + (Ne^{q+})^* \]  

(39)

In the paper of Hatton et. al. (1981), the electron-ion interaction was assumed to be the following form of the exponentially screened Coulomb potential:

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\[ V(\vec{r}_1, \vec{r}_2) = \left( \frac{Ze}{r_1} - \frac{e}{|r_1 - r_2|} \right) \exp \left( -\frac{r_1}{D} \right), \quad (40) \]

where \( D \) is the Debye-Hückel screening length, given in Eq. (8), \( \vec{r}_1 \) and \( \vec{r}_2 \) are the position vectors of the projectile electron and the bound electron, respectively. The cross sections for the \( 1s+2s \) and the \( 1s+2p \) excitations have been obtained. In the relation between the collision strength \( \Omega \) and the incident kinetic energy \( E \), the scaling relation of \( Z^2\Omega \) and \( E/Z^2 \) gives general schemes. The curves of the collision strength for the \( 1s+2s \) and the \( 1s+2p \) excitation processes are shown in Fig. 7 and 8 with various \( DZ \) parameters, respectively. The effect of the plasma environment is to appreciably reduce cross sections just above threshold.

Davis and Blaha (1982) have also investigated the same excitation processes for a impurity neon as those examined by Hatton et. al. (1981). They took an electrostatic potential of the charged particles \( Ze \) as

\[ V(r) = Z e^{-1} - 4\pi e \left[ \int_0^r dr \left( \rho_b + \rho_f + \rho_i \right) + \int_r^\infty dr' \left( \rho_b + \rho_f + \rho_p \right) \right] \]  

\[ + \int_0^r r' \left( \rho_b + \rho_f + \rho_p \right) dr' \]  

(41)

\[ \text{The positive charge distribution } \rho_i \text{ was assumed to be} \]

\[ \rho_i = \rho_{\infty} \exp \left( -eV(r)/kT \right) \]  

(42)
where $V(r)$ is given in Eq. (40) and $\rho_\infty$ is the average charge density in plasma. The free electron density with wavevector $\vec{k}$ is considered to be distributed in the Fermi statistical law of Eq. (11). By solving the two sets of the Schrödinger equations for the bound and the free electrons self-consistently, the scattering lengths for excitation processes of the $1s+2s$ and the $1s+2p$ were obtained. The calculated collision strength at $T_e=200$ eV is also reduced near the threshold.

3-f) Stopping Power

In recent years there has been a growing interest in the stopping power in hot, dense plasma, since ion beams are also be used as an ICF driver. Recently the stopping power for some heavy ions in various cold target materials has been measured by Bimbot et al. (1980) with the ion energies up to 5 MeV/amu and by Hubert et al. (1980) with those 2.5-100 MeV/amu. Some of these results are quite different from those of Northcliffe et al. (1970).

The dominant mechanism of the stopping power in a plasma is the energy loss of the projectile ion through the collision with plasma electrons in the Debye sphere and the excitation of plasmons out of the sphere. Mehlhorn (1981) and Meyer-ter-Vehn and Metzher (1981) have extended the standard theory of the stopping power for cold materials by Jackson (1962) to the partially ionized dense plasmas. The total stopping power $S$ for a plasma can be expressed as a sum of the bound-electron $S_b$, free-electron $S_f$ and plasma-ion $S_i$ stopping powers:

$$S = S_b + S_f + S_i$$

\(\text{(43)}\)
The stopping power of the bound electrons $S_b$ is written as

$$S_b = \text{Min. } (S_{\text{Bethe}}, S_{\text{LSS}}) + S_{\text{nucl}},$$  \hspace{1cm} (44)\]

where $S_{\text{nucl}}$ denotes the nuclear stopping power. The notation of $\text{Min. } (S_{\text{Bethe}}, S_{\text{LSS}})$ in Eq. (44) indicates the smaller value between the stopping-power formula of Bethe $S_{\text{Bethe}}$ and the formula of Lindhard, Scharff and Schiott (1963) $S_{\text{LSS}}$. $S_{\text{Bethe}}$ accounts for both ionizations and excitations of the atomic electrons, whereas $S_{\text{LSS}}$, which is derived by use of the imaginary part of the dielectric function for the electron gas, calculates the electronic stopping power for low-energy projectile ions. When a heavy projectile ion with the very low incident energy passes through the plasma of heavy elements, the slowdown of the incident ion due to the elastic Coulomb collisions with the plasma ions becomes significant. In this case, the nuclear stopping power $S_{\text{nucl}}$ is not neglected as a small value compared with the electronic stopping power. The difference of the theory between Mehlhorn and Meyer-ter-Vehn et. al. lies in the use of different effective charge $q_{\text{eff}}$ of the projectile ion appearing in $S_{\text{Bethe}}$: The stopping power increases in proportion to the square of $q_{\text{eff}}$. Using Jackson' formula, Mehlhorn (1981) has also given the formulae for the stopping power of free plasma electrons $S_f$ and of the plasma ions $S_i$ in the binary collision theory.

Recently Maynard et. al. (1982) have proposed a method to calculate the electronic stopping power for nonrelativistic charged particles in dense electron fluids by using the exact random-phase-approximation (RPA).
dielectric function. This approach implicitly contains both binary and collective processes. Maynard et al. have given some numerical examples for the stopping power of very dense electron fluids, which is shown in Fig. 9. This figure shows that the temperature effect is important for ions with a few MeV per nucleon around $T_e = \varepsilon_F$. As is expected, the stopping power is a decreasing function of the temperature.

The theoretical stopping powers obtained as a scaled form with respect to the atomic number of the projectile ion and/or the plasma ions described above are not compared with experiment yet.
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Figure Captions

**Fig. 1** Dependence of the energy levels on the screening lengths for the six lowest-lying states (Rogers et al. 1970).

**Fig. 2** Dependence of the energy levels on the screening lengths for some of the higher-lying states (Rogers et al. 1970).

**Fig. 3** Spontaneous-emission transition probabilities in the dipole approximation for the Debye-Hückel (DH) potential is shown as a function of the DH screening length (Roussel et al. 1974).

**Fig. 4** Averaged oscillator strengths $\sigma_{n\ell}(\omega)$ for the Debye-Hückel potential for different values of $D$ and $R$, respectively (Höhne et al. 1982): Crosses, $\sigma$ at discrete lines; full curve, continuum. The monotonically decreasing curves show the Coulomb function $\sigma_{n\ell}^{\text{Coul}}(\omega)$. Arrows denote the line positions of the unscreened Coulomb potential. Note the shifted zero for different parameters.

**Fig. 5** Lyman-α line shift for neon impurity in a dense plasma at $kT=750$ eV (Gupta et al. 1982). S-Skupsky (1980); DH-'linearized Debye-Huckel' (Skupsky 1980); NLDH-'non-linear Debye-Hückel' (Gupta et al. 1981); open circles-$V_{\text{eff}}$ (Gupta et al. 1981); solid curve-Cauble (1982).
Fig. 6 Gaunt factors for cesium at 1 keV temperature and 1.9 g/cm$^3$ density, as a function of the fraction $h\nu/W_0$ of incident energy radiated by the photon ($W_0=1$ keV) (Lamoureux et al. 1982). Dotted line (...) : Coulomb Born approximation result $g^B$; dashed line (-----): Born approximation result $g^B_{SCFAA}$ from the SCFAA potential $V_{SCFAA}$ of Rozsnyai (1979); solid line (----): relativistic partial wave expansion results using the Thomas-Fermi potential $V_{TF}$; dash-dotted line (---) : relativistic partial wave expansion results using $V_{SCFAA}$.

Fig. 7 Total collision strengths $Z^2\Omega$ as a function of energy $E/Z^2$ (in a.u.) for the 1s+2s transition for screening lengths $DZ=10, 20, 50, 100$ and $\infty a_0$ (------) (Hatton et al. 1981). Results corresponding to screened target-state energies for $DZ=10 a_0$ and 20 $a_0$ are above the respective unscreened energies curves. CBI results for $Z=2$ are also shown.

Fig. 8 Total collision strengths $Z^2\Omega$ as a function of energy $E/Z^2$ (in a.u.) for the 1s+2p transition for screening lengths $DZ=10, 20, 50$, and $\infty a_0$ (------) (Hatton et al. 1981). Results corresponding to screened target-state energies for $DZ=10 a_0$ (closed circles) are above the respective unscreened energies curves. CBI results for $Z=2$ are also shown.

Fig. 9 Stopping power dE/dx (a.u.) at $N_e=10^{25}/cm^3$ and various temperatures (Maynard et al. 1982).
Fig. 1

Fig. 2
Fig. 3
Fig. 4
Fig. 5
Fig. 6

$Cs (Z = 55)$

$W_o = 1 \text{ keV}$

Graph showing the relationship between $G$ and $h\nu/W_o$ with curves for $G^B$, $G^B_{\text{SCFAA}}$, $G_{\text{TF}}$, and $G_{\text{SCFAA}}$. The graph indicates variation in the Gount Factor $G$ as a function of $h\nu/W_o$. The Kramers Value is marked on the graph.
Fig. 7

Fig. 8
Fig. 9

- $T_e = 0.78817 \ (1.51 \times 10^4 \ K)$
- $T_e = 0.98874 \ (1.96 \times 10^4 \ K)$
- $T_e = 2.3607 \ (4.88 \times 10^4 \ K)$
- $T_e = 0.000 \ (0 \ K)$

$n \times 10^{15} \text{e cm}^{-3}$

$E \ (\text{MeV/amu})$
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